



20V P-Channel Enhancement Mode MOSFET - ESD Protected

Voltage -20 V

Current

-4.3A

Features

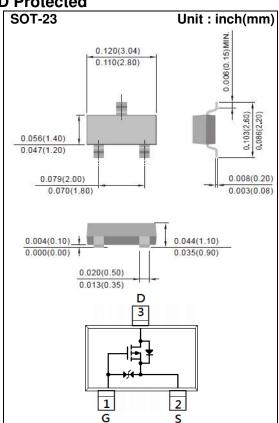
- $R_{DS(ON)}$, V_{GS} @-4.5V, I_{D} @-4.3A<52m Ω
- $R_{DS(ON)}$, V_{GS} @-2.5V, I_{D} @-3.0A<60m Ω
- $R_{DS(ON)}$, V_{GS} @-1.8V, I_{D} @-1.5A<80m Ω
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected 2KV HBM
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: SOT-23 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0003 ounces, 0.0084 grams



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	-20	V	
Gate-Source Voltage		V_{GS}	<u>+</u> 8		
Continuous Drain Current		I _D	-4.3	A	
Pulsed Drain Current		I _{DM}	-17.2		
Power Dissipation	T _a =25°C	P _D	1.25	W	
	Derate above 25°C		10	mW/°C	
Operating Junction and Storage Temperature Range		T_{J} , T_{STG}	-55~150	°C	
Typical Thermal Resistance - Junction to Ambient (Note 3)		$R_{ heta JA}$	100	°C/W	





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-20	-	- V		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=-250uA$		-0.72	-1.0	V	
Drain-Source On-State Resistance	R _{DS(on)}	V_{GS} =-4.5V, I_{D} =-4.3A	-	44	52		
		V_{GS} =-2.5V, I_{D} =-3.0A	-	53	60	mΩ	
		V _{GS} =-1.8V, I _D =-1.5A	-	70	80		
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =-20V, V_{GS} =0V	-	-	-1	uA	
Gate-Source Leakage Current	I _{GSS}	$V_{GS} = \pm 8V, V_{DS} = 0V$	-	-	<u>+</u> 10		
Dynamic (Note 5)							
Total Gate Charge	Q_{g}	101/ 1 104	-	24	-	nC	
Gate-Source Charge	Q_gs	V_{DS} =-10V, I_{D} =-4.3A, V_{GS} =-4.5V (Note 1,2)	-	1.5	-		
Gate-Drain Charge	Q_{gd}	V _{GS} =-4.5 V	-	2.5	-		
Input Capacitance	Ciss	\/ 40\/ \/ 0\/	-	907	-	pF	
Output Capacitance	Coss	V_{DS} =-10V, V_{GS} =0V,	-	90	-		
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	70	-		
Turn-On Delay Time	td _(on)	\/ 10\/ L 40A	-	45	-		
Turn-On Rise Time	tr	V_{DD} =-10V, I_{D} =-4.3A,	-	79	-	ns	
Turn-Off Delay Time	td _(off)	V_{GS} =-4.5V, R_{G} =6 Ω (Note 1,2)	-	193	-		
Turn-Off Fall Time	tf	11G=012	-	826	-		
Drain-Source Diode							
Maximum Continuous Drain-Source Diode Forward Current	Is		-	-	-1.5	Α	
Diode Forward Voltage	V_{SD}	I _S =-1.0A, V _{GS} =0V	-	-0.76	-1.2	V	

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited
- 5. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

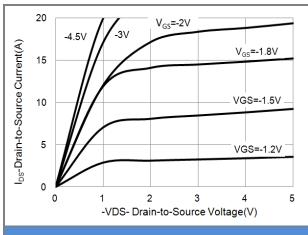


Fig.1 On-Region Characteristics

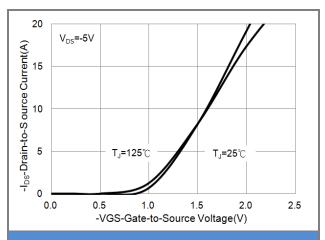


Fig.2 Transfer Characteristics

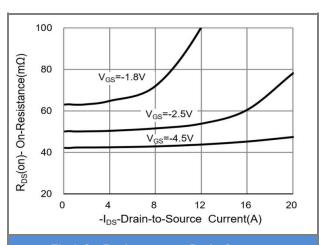


Fig.3 On-Resistance vs. Drain Current

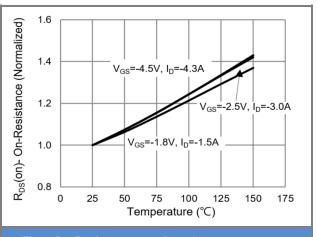


Fig.4 On-Resistance vs. Junction temperature

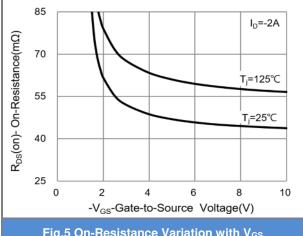


Fig.5 On-Resistance Variation with V_{GS}

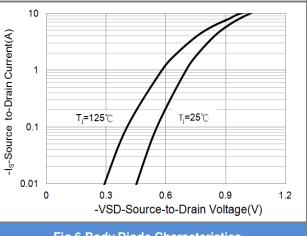


Fig.6 Body Diode Characteristics





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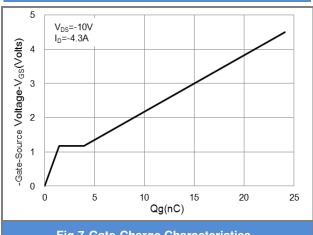


Fig.7 Gate-Charge Characteristics

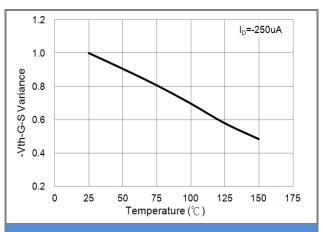


Fig.8 Threshold Voltage Variation with Temperature

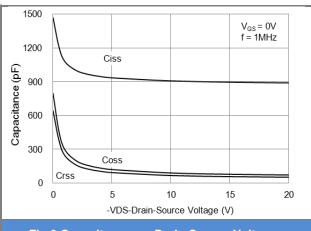


Fig.9 Capacitance vs. Drain-Source Voltage

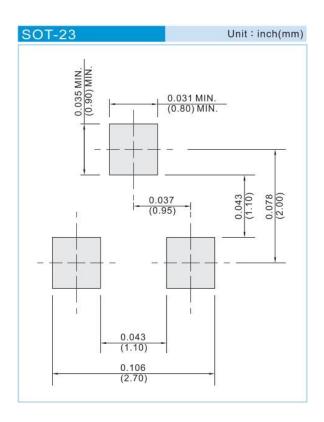




Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJA3415AE-AU_R1_000A1	SOT-23	3K pcs / 7" reel	A5AE	Halogen free

Mounting Pad Layout







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